

MIP160, MIP162, MIP163, MIP164, MIP165, MIP166

Silicon MOS IC

■ Features

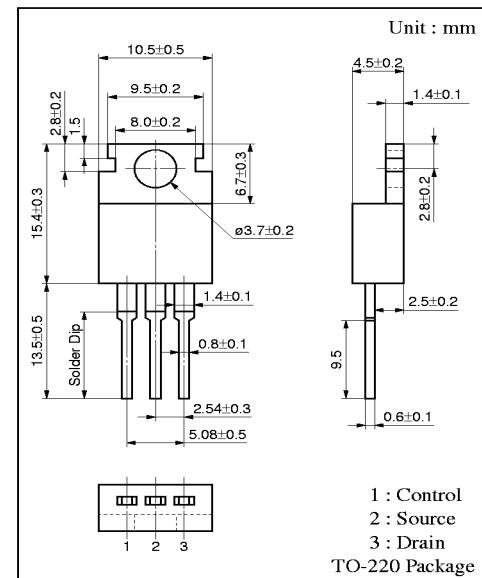
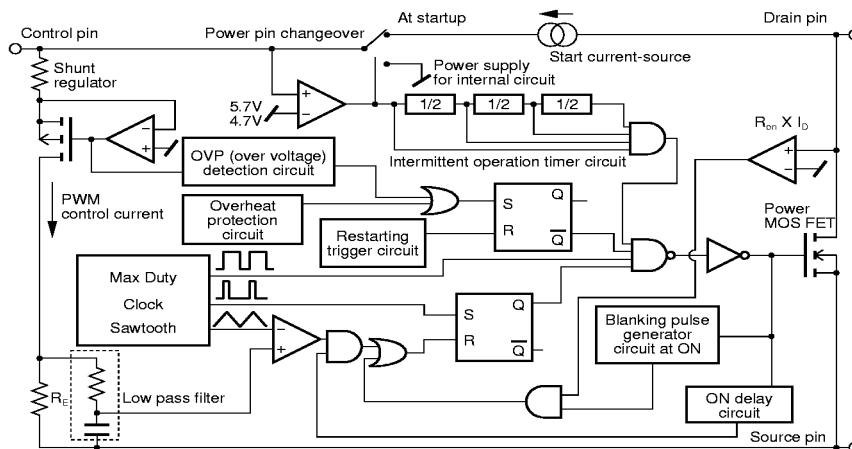
- Single chip IC with high breakdown voltage power MOS FET and CMOS control circuit
- Worldwide input (85 to 274VAC) possible
- Over-voltage protection at secondary section, pulse by pulse over-current protection, and intermittent operation timer at overload

■ Applications

- Switching mode regulator (5 to 40W)
- AC adapter
- Battery charger

■ Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Rating	Unit
Drain voltage	V _D	700	V
Control voltage	V _C	8	V
Output current	I _D	I _{LIMIT}	A
Control current	I _C	0.1	A
Allowable power dissipation	P _D	1.7/12.5 * ¹	W
Operating ambient temperature	T _{opr}	- 20 to + 85	°C
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	- 55 to +150	°C

* 1 : T_C= 25°C**■ Block Diagram**

■ Electrical Characteristics ($T_c = 25 \pm 2^\circ\text{C}$)

	Parameter	Symbol	Condition	Min	Typ	Max	Unit	
Control function	Output frequency	f_{osc}	$I_C = 4\text{mA}$	90	100	110	kHz	
	Maximum duty cycle	MAXDC	$I_C = 2\text{mA}$	64	67	70	%	
	Minimum duty cycle	MINDC	$I_C = 10\text{mA}$	1	2	3	%	
Start up	Control pin charge current		I_C	$V_C = 0\text{V}$	-2.4	-1.9	-1.2	
				$V_C = 5\text{V}$	-2.0	-1.5	-0.8	
Start up	Control pin voltage at startup	$V_C(\text{ON})$		5.0	5.7	6.3	V	
	Control pin voltage at stop	$V_C(\text{OFF})$		4.0	4.7	5.3	V	
	Start/stop hysteresis voltage	ΔV_C		0.5	1.0	1.5	V	
	Intermittent operation time-ratio	T_{SW}/T_{TIM}			5	8	%	
	Intermittent operation frequency	f_{TIM}		0.5	1.2	2.0	Hz	
	Over current protection/detection	MIP160	I _{LIMIT}		0.415	0.5	0.585	
Protection function		MIP162			0.75	0.9	1.05	
		MIP163			1.12	1.35	1.57	
		MIP164			1.35	1.62	1.89	
		MIP165			1.88	2.25	2.63	
		MIP166			2.4	2.8	3.2	
Protection function	Blanking width at ON	$t_{on(\text{BLK})}$	$I_C = 4\text{mA}$		0.25		μs	
	Over current protection delay time	$t_d(\text{OCL})$	$I_C = 4\text{mA}$		0.1		μs	
	Over current protection temperature	T_{OTP}	$I_C = 4\text{mA}$	130	140	150	$^\circ\text{C}$	
	Over voltage protection/detection current	I_{ovp}		25	45	75	mA	
	Latch reset voltage	$V_C(\text{reset})$		2.3	3.3	4.2	V	
	ON resistance	MIP160	R _{D(S(ON))}	0.1A		15	18	
		MIP162		0.3A		8.5	10	
		MIP163		0.3A		5.8	6.7	
		MIP164		0.5A		4.5	5.5	
		MIP165		0.8A		3.0	3.8	
		MIP166		1.0A		2.6	3.3	
Output	Drain pin leak current at OFF	I_{DSS}	$V_{DS} = 650\text{V}, I_C = 4\text{mA}$ latch mode		0.5	0.9	mA	
	Drain breakdown voltage	V_{DSS}	$I_C = 4\text{mA}, I_D = 0.25\text{mA}$ latch mode	700			V	
	Rise time	t_f			0.1	0.2	μs	
	Fall time	t_r			0.1	0.2	μs	
	Minimum drain voltage	$V_{D(\text{MIN})}$		36			V	
Supply voltage	Shunt regulator voltage	V_C	$I_C = 4\text{mA}$	5.5	5.8	6.1	V	
	Control pin discharge current	I_{CD1}	at output MOS operation	0.7	1.4	1.8	mA	
		I_{CD2}	at output MOS stop	0.5	0.8	1.1	mA	